

isc N-Channel MOSFET Transistor

IXTP86N20T

FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \leq 29 m \Omega @V_{GS} = 10 V$
- Fully characterized avalanche voltage and current
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



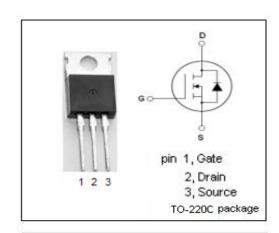
- DC/DC Converters
- · High Speed Power Switching Applications

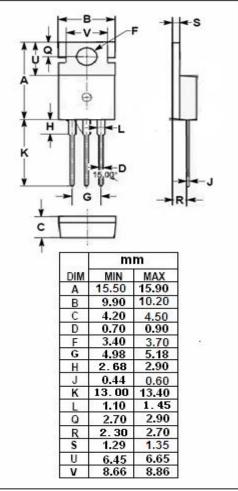
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|---------|------------------------|
| V _{DSS} | Drain-Source Voltage | 200 | V |
| V _{GS} | Gate-Source Voltage | ±30 | V |
| I _D | Drain Current-Continuous | 86 | А |
| I _{DM} | Drain Current-Single Pulsed | 260 | А |
| P _D | Total Dissipation @T _C =25℃ | 300 | W |
| Tj | Operating Junction Temperature | -55~175 | °C |
| T _{stg} | Storage Temperature | -55~175 | $^{\circ}\!\mathbb{C}$ |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT | |
|----------------------|-------------------------------------|-----|------|--|
| R _{th(j-c)} | Junction-to-case thermal resistance | 0.5 | °C/W | |







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ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|---------------------|--------------------------------|--|-----|------|-------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0V; ID = 250 μ A | 200 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = V _{GS} ; ID = 1mA | 3.0 | 5.0 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D = 43A | | 29 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V;V _{DS} =0V | | ±200 | nA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} = V _{DSS} ; V _{GS} = 0V | | 1 | - μ Α |
| | | V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 125°C | | 250 | |
| VsD | Diode forward voltage | I _F = 86A; V _{GS} = 0V | | 1.5 | V |



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